NSN 5961-01-463-0611 Transistor - Page 1 of 1



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View Online at https://aerobasegroup.com/nsn/5961-01-463-0611	
Inclosure Material:	
Glass	
Overall Length:	
1.400 millimeters	
End Application:	
6625-01-425-2551	
Mounting Facility Quantity:	
3	
Mounting Method:	
Terminal	
Semiconductor Material:	
Silicon alloy	
Voltage Rating In Volts Per Characteristic:	
-15.0 collector to base voltage/static/emitter open and -15.0 collector-to-emitter, substaining voltage, base open-circuited and -4.5 emitter.	te
to base voltage, static, collector open	
Current Rating Per Characteristic:	
Between -50.00 milliamperes source cutoff current and -100.00 nanoamperes source cutoff current and -100.00 nanoamperes source cutoff	0
current universal	
Power Rating Per Characteristic:	
200.0 milliwatts small-signal input power, common-emitter absolute	
Maximum Operating Tempurature Per Measurement Point:	
150.0 degrees celsius junction	
Terminal Type And Quantity:	
3 uninsulated wire lead	
Shelf Life:	
N/a	
Unit Of Measure:	
	
Demilitarization:	
No	
Filig:	
A110a0	